## **NSPAS3M Series**



# **Automotive Absolute Pressure Sensor**

Datasheet (EN) 2.1

#### **Product Overview**

NSPAS3M is a calibrated absolute pressure sensor series product launched by NOVOSENSE for powertrain applications. This series uses an automotive-grade ASIC to calibrate and compensate the MEMS sensor element, the pressure signal from 10kPa to 400kPa can be converted into an analog output signal (0~5V) with a customizable output range. While ensuring the reliability of the product, the two chips are integrated and packaged, reduces the package size greatly. This series provides outstanding performance in terms of initial accuracy and suits applications with harsh automotive temperature and stress conditions needing small drift over lifetime. Reliability test according to AEC-Q100 standard.

### **Key Features**

- High precision pressure sensing Better than ±1.5%F.S. (0°C to 85°C)
   Better than ±2.0%F.S. (-40°C to 125°C)
- Large temperature range -40°C to 125°C
- Over-voltage and Reverse voltage protection between -24V to 28V
- Better than 1ms response time
- Ratio-metric/Absolute analog output
- Clamping
- AEC-Q100 qualified

## **Applications**

- Motorcycle TMAP applications
- Temperature manifold pressure sensor (TMAP1)
- ECU barometric absolute pressure (ECU-BAP)
- Canister desorption pressure detection
- Battery pressure sensor
- Seat airbag pressure detection
- Industrial control
- 1. **Not suitable** for **harsh media applications** like fresh air mixed with high concentrations of corrosive gases such as engine exhaust gas or halogens.

#### **Device Information**

Part Number	Package	Body Size
NSPAS3M	7070SOP8	7.0mm × 7.0mm

#### **Outline**



# **NSPAS3M Series**

# **INDEX**

1. PIN CONFIGURATION AND FUNCTIONS	3
2. ABSOLUTE MAXIMUM RATINGS	4
3. RECOMMENDED OPERATING CONDITIONS	4
4. SPECIFICATIONS	5
4.1. ELECTRICAL CHARACTERISTICS	5
5. FUNCTION DESCRIPTION	6
5.1. OVERVIEW	6
6. TYPICAL APPLICATION	9
6.1. APPLICATION CIRCUIT	0
7. PACKAGE INFORMATION	
8. ORDER INFORMATION	2
9. IDENTIFICATION CODE	
10. TAPE/REEL INFORMATION	4
11. REVISION HISTORY	5

# 1. Pin Configuration and Functions

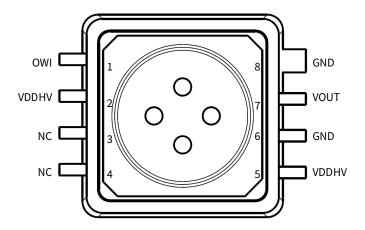


Fig 1.1 Pin Definition (Top view)

Table 1.1 Pin Description

Pin No.	Pin Name	Description
1	OWI	One-wire interface (leave floating)
2	VDDHV	Power supply with OVP/RVP
3	NC	No connect
4	NC	No connect
5	VDDHV	Power supply with OVP/RVP
6	GND	Ground
7	VOUT	Analog output
8	GND	Ground

# 2. Absolute Maximum Ratings

Parameters	Symbol	Min	Тур	Мах	Unit	Comments
Supply voltage	VDDHV	-24		28	V	70°C, 1 hour
		-30		36	V	70°C, 1 minute
Analog pin voltage	VOUT	-0.3		5.3	V	25°C, VDDHV>5V
Analog output current limit				25	mA	
Proof pressure	P <sub>proof</sub>	1000			kPa	
Burst pressure	P <sub>burst</sub>	1500			kPa	
ESD susceptibility	НВМ	±2			kV	
	CDM	±750			V	Corner pins
	CDM	±500			V	All other pins
Storage temperature	Tstg	-40		125	°C	

# **3. Recommended Operating Conditions**

Parameters	Symbol	Min	Тур	Мах	Unit	Comments
Supply voltage	VDDHV	4.5	5	5.5	٧	
Operating pressure	P <sub>amb</sub>	10		400	kPa	
Operating temperature	Topr	-40		125	°C	

# 4. Specifications

## 4.1. Electrical Characteristics

Parameters	Symbol	Min	Тур	Max	Unit	Comments
Output voltage range	VOUT	0.05		4.95	V	
Accuracy pressure <sup>1</sup>	Acc	-1.5%		1.5%	%F.S.	@0°C ~85°C
		-2.0%		2.0%	%F.S.	@-40°C ~125°C
Power on reset	VDDHV <sub>POR</sub>		2.5		٧	
Operating current <sup>2</sup>	l <sub>avdd</sub>	2.5	3.1	3.7	mA	@25°C
Output RMS noise	$V_{rms}$		0.5		mV	
Output load resistance	R <sub>load</sub>	1			kOhm	
Output load capacitance	C <sub>load</sub>			150	nF	
Output short current limit	I <sub>short_lmt</sub>	10		25	mA	Output short to VDDHV or GND
Clamp low level	$V_{clampl}$	0%		50%	%VDDHV	
Clamp high level	$V_{clamph}$	50%		100%	%VDDHV	
Clamp level error	$\Delta V_{clamp}$		40		mV	@VDDHV=5V
Power up time <sup>2</sup>	$T_UP$	8	10	12	ms	@25°C
Response time	T <sub>RESP</sub>		1		ms	
Diagnostic response time	$T_{diag}$			1	ms	
EEPROM data retention	$T_{live}$	10			years	@150°C

<sup>1.</sup> Pressure accuracy is qualified with part number NSPAS3M115RRG1. For pressure accuracy of different part number, please refer to complete part number list at chapter 8.

<sup>2.</sup> These characteristics are tested at room temperature.

## 5. Function Description

#### 5.1. Overview

NSPAS3M uses a MEMS piezoresistive absolute pressure sensor element as a pressure sensitive component that provide an original signal output that is proportional to ambient pressure. The built-in conditioning IC drives the sensitive component and amplifies, temperature compensates, and linearizes the original signal to output a voltage signal that is linear with the applied pressure.

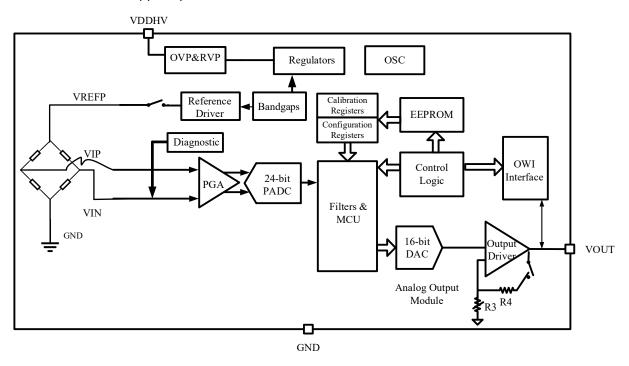


Fig 5.1 Product Function Block Diagram

#### 5.2. Transfer Function

NSPAS3M series device is fully calibrated on delivery. The sensor has a linear transfer function between the applied pressure and the output signal:

Ratiometric: VOUT = (A X P + B) X VDDHV

Absolute: VOUT = (AXP + B)X5

Note: 1) P is the pressure value, absolute pressure, range: 10kPe~400kPa; the transfer function is only established in the pressure range.

2) VDDHV must in the operating voltage range;

Table 5.1 NSPAS3M115RRD1 Transfer Function Coefficient

Product Type	Pressure range		Output range		Gain and offset		
	$P_L$	$P_H$	$O_L$	Он	Α	В	
NSPAS3M115RRD1	10kPa	115kPa	0.4V	4.65V	0.008095	-0.00095	

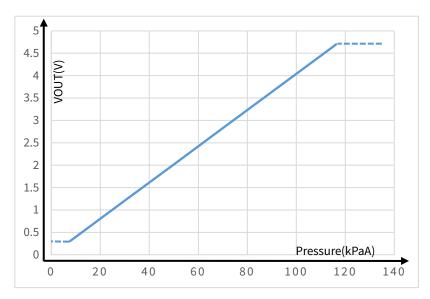


Fig 5.2 NSPAS3M115RRD1 Transfer Function

#### 5.3. Accuracy

Factors affecting the accuracy of NSPAS3M series products include power supply voltage (ratiometric error), pressure, temperature and aging effects. Standard output refers to the theoretical voltage output calculated by the transfer function of the pressure in the range. The error equals the deviation between the measured output voltage value and the specified output voltage value. The accuracy in the following analysis is in a typical application circuit.

#### 5.3.1 Ratiometric Error

Ideally the sensor is ratiometric - the output (VOUT) scales by the same ratio that VDDHV increases or decreases. The ratiometric error is defined as the difference between the ratio that VDDHV changed and the ratio that VOUT changed, expressed as a percentage. The calculation formula is as follows:

$$E_{RAT}(\%) = (VOUT(@VDDHV) - VOUT(@5V) \times VDDHV/5V) / 5V) \times 100\%$$

The output voltage VOUT is ratiometric to VDDHV. VDDHV must be in the operating range.

Table 5.2 Ratiometric Output Error

Supply Voltage (V)	Max. Ratiometric Error E <sub>RAT</sub> (%) @ VDDHV <sub>TYP</sub>
VDDHV <sub>MIN</sub>	±0.5%
$VDDHV_{TYP}$	0
VDDHV <sub>MAX</sub>	±0.5%

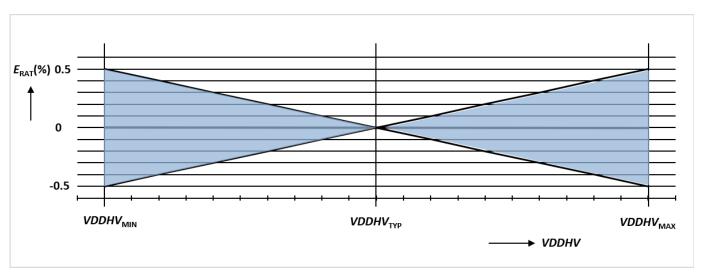


Fig 5.3 Ratiometric Error

#### **5.3.2 Overall Accuracy**

The accuracy error includes errors introduced by all influencing factors within the operating range of pressure and temperature, including:

Pressure:

Output deviation from target transfer function over the specified pressure range

Temperature:

Output deviation over the temperature range

Aging:

Parameter drift over life time

Ps: Ratiometric signal error is not included in the overall accuracy. For error measurements, the supply voltage must have the nominal value (VDDHV = 5V).

Table 5.3 Accuracy

Temperature (°C)	Error (%F.S.)
-40	2.00
0	1.50
85	1.50
125	2.00

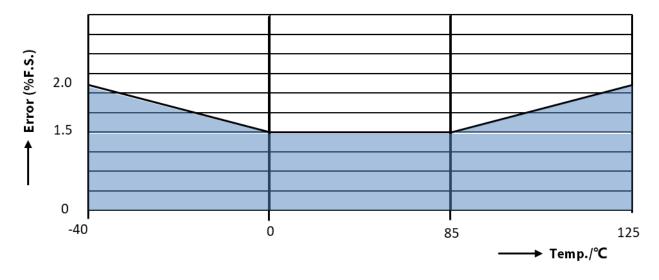


Fig 5.4 Accuracy for Pressure Acquisition

# 6. Typical Application

### 6.1. Application Circuit

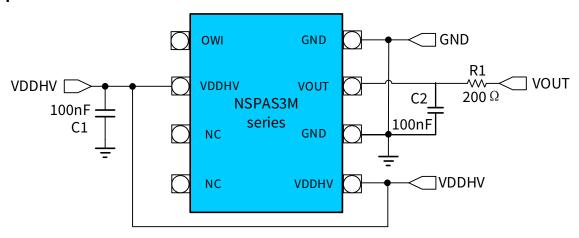


Fig 6.1 Application Circuit

#### Note:

- 1) For applications with higher ESD requirements, can add TVS between VOUT and GND and between VDDHV and GND.
- 2) Please contact NOVOSENSE for detailed peripheral recommended circuit.

## **6.2. Recommended Footprint**

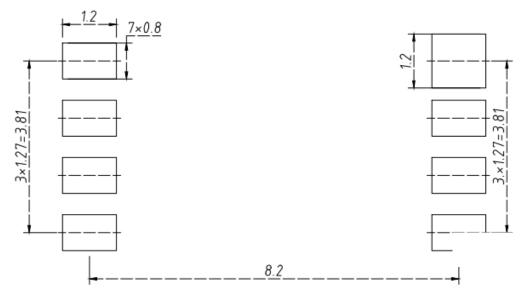


Fig 6.2 Footprint mm

# **6.3. Soldering Parameters**

Table 6.1 Soldering Parameters

Re	Reflow Condition					
	Temperature Min (Ts(min))	150°C				
Pre Heat	Temperature Max (Ts(max)	200°C				
	Time (min to max) (ts)	60 – 180 secs				
Average ramp up rate (L	iquidus Temp (T∟) to peak	3°C/second max				
T <sub>s</sub> (max)to T <sub>L</sub> - F	Ramp-up Rate	3°C/second max				
Reflow	Temperature (T∟) (Liquidus)	217°C				
Renow	Time (min to max) (t∟)	60 – 150 seconds				
Peak Temperature (T <sub>P</sub> )		260°C				
Time within 5°C of actu	al peak Temperature (tp)	20 – 40 seconds				
Ramp-down Rate	Ramp-down Rate					
Time 25°C to peak Tem	8 minutes Max.					
Do not exceed		260°C				

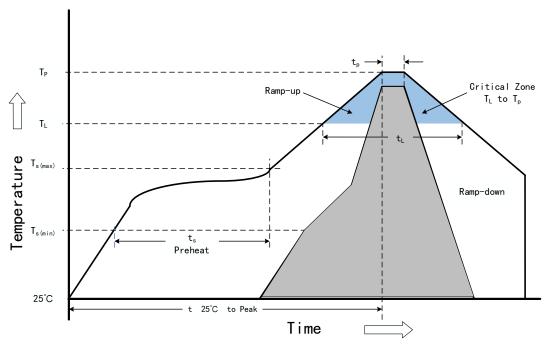
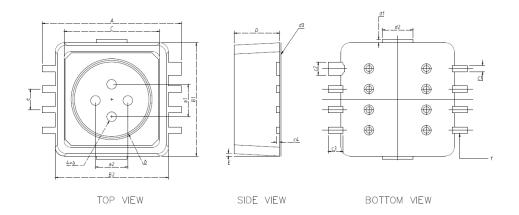


Fig 6.3 Soldering Profile

# 7. Package Information



CONTROLLING DIMENSION: MM

	N	IILLMETR	E				
SYMBOL	MIN	NOM	MAX				
Α	8.5	8.6	8.7				
B1	6.9	7.0	7.1				
В2	6.9	7.0	7.1				
С	5.8	5.9	6.0				
D	2.7	2.8	2.9				
Ε	1°	3*	5*				
а	Ø0.5	Ø0.6	Ø0.7				
a1	1.9	2	2.1				
a2	1.9	2	2.1				
b	ø4.7	ø4.8	ø4.9				
с1	0.35	0.4	0.5				
c2	0.75	0.8	0.9				
сЗ	0.9	1.0	1.1				
с4	0.15	0.2	0.3				
d1	BUF	RR MAX	0.2				
d2	BUF	RR MAX	1.9				
d3	PLASTIC PROTRUSION OF 0.03MAX						
е		1.27 bac	:				
f		PAD FL 0.1 MAX					

Fig 7.1 Package Outline mm

## 8. Order Information

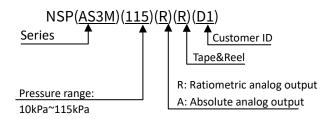
		Pressui	re Range	Output	Range	Clamp	Level	Gain and	d Offset	Supply	oply Accuracy	
Product Type	Output Type	$P_L$	Рн	OL	Он	$V_{CL}$	V <sub>CH</sub>	Α	В	Voltage	0~85℃	-40~125℃
NSPAS3M115RR05	Ratiometric	40.00kPa	115.00kPa	0.200V	4.700V	0.20V	4.70V	0.001200	-0.440000	5.0V	±1.5%	±2.0%
NSPAS3M250RR08	Ratiometric	15.00kPa	250.00kPa	0.315V	4.310V	0.30V	4.70V	0.003400	-0.012000	5.0V	±1.5%	±2.0%
NSPAS3M115RRA1	Ratiometric	10.00kPa	115.00kPa	0.400V	4.650V	0.30V	4.70V	0.008095	-0.000952	5.0V	±1.5%	±2.0%
NSPAS3M115RRD1	Ratiometric	10.00kPa	115.00kPa	0.400V	4.650V	0.30V	4.80V	0.008095	-0.000952	5.0V	±1.5%	±2.0%
NSPAS3M250RRD3	Ratiometric	20.00kPa	250.00kPa	0.400V	4.650V	0.30V	4.80V	0.003696	0.006087	5.0V	±1.5%	±2.0%
NSPAS3M107RRD4	Ratiometric	13.30kPa	106.70kPa	0.500V	4.600V	0.33V	4.73V	0.008779	-0.016767	5.0V	±1.5%	±2.0%
NSPAS3M350RRD6	Ratiometric	44.80kPa	350.00kPa	0.500V	4.500V	0.30V	4.70V	0.002621	-0.017431	5.0V	±1.5%	±2.0%
NSPAS3M165RRE1	Ratiometric	60.00kPa	165.00kPa	0.200V	4.800V	NA	NA	0.008762	-0.485714	5.0V	±1.5%	±2.0%
NSPAS3M115RRG1	Ratiometric	20.00kPa	115.00kPa	0.400V	4.650V	0.30V	4.70V	0.008947	-0.098947	5.0V	±1.5%	±2.0%
NSPAS3M115RRK2	Ratiometric	15.00kPa	115.00kPa	0.180V	4.650V	0.10V	4.85V	0.008940	-0.098100	5.0V	±1.5%	±2.0%

Please scan the following QR code or visit the download link for complete part number list.

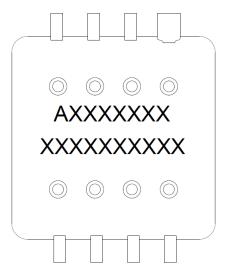
https://www.novosns.com//Public/Uploads/uploadfile4/nspas3m-series.pdf



Naming Convention:



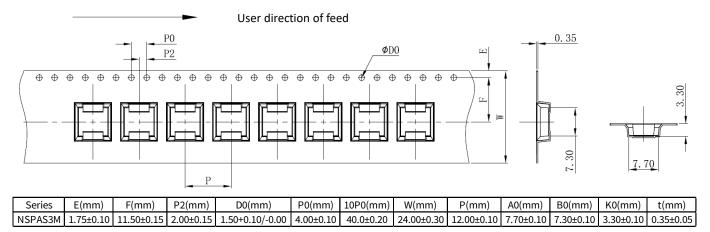
# 9. Identification Code



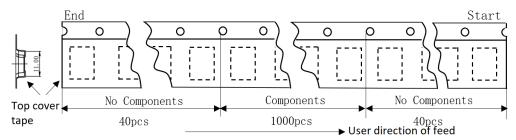
AXXXXXXX: Package lot number.

XXXXXXXXX: Product serial number.

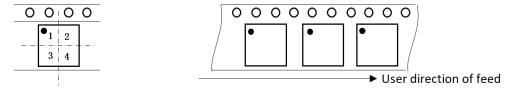
# 10. Tape/Reel Information



There is no component at the head and the tail of each tape/reel, where the space is 40pcs, as shown in the following figure.



Pin8 is located at the second quadrant, as shown in the following figure.



Minimum ordering quantity(MOQ):1000EA.

Standard pack quantity(SPQ): 1000EA.

# **11. Revision History**

Revision	Description	Date
1.0	First Release	2023/07/25
1.1	Update Order Information	2023/10/07
1.2	Update Order Information;	2023/10/12
	Update Identification Code.	
2.0	Formal Release	2023/10/31
2.1	Add comments for TMAP application; remove VBS application; simplify naming	2024/4/24
	convention.	

#### IMPORTANT NOTICE

The information given in this document (the "Document") shall in no event be regarded as any warranty or authorization of, express or implied, including but not limited to accuracy, completeness, merchantability, fitness for a particular purpose or infringement of any third party's intellectual property rights.

Users of this Document shall be solely responsible for the use of NOVOSENSE's products and applications, and for the safety thereof. Users shall comply with all laws, regulations and requirements related to NOVOSENSE's products and applications, although information or support related to any application may still be provided by NOVOSENSE.

This Document is provided on an "AS IS" basis, and is intended only for skilled developers designing with NOVOSENSE's products. NOVOSENSE reserves the rights to make corrections, modifications, enhancements, improvements or other changes to the products and services provided without notice. NOVOSENSE authorizes users to use this Document exclusively for the development of relevant applications or systems designed to integrate NOVOSENSE's products. No license to any intellectual property rights of NOVOSENSE is granted by implication or otherwise. Using this Document for any other purpose, or any unauthorized reproduction or display of this Document is strictly prohibited. In no event shall NOVOSENSE be liable for any claims, damages, costs, losses or liabilities arising out of or in connection with this Document or the use of this Document.

For further information on applications, products and technologies, please contact NOVOSENSE (www.novosns.com).

Suzhou NOVOSENSE Microelectronics Co., Ltd